## 2SC3338

Silicon NPN Epitaxial

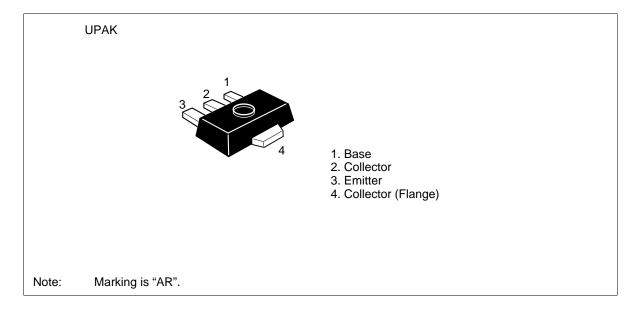
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ADE-208-1081 (Z) 1st. Edition Mar. 2001

#### Application

UHF / VHF wide band amplifier

#### Outline





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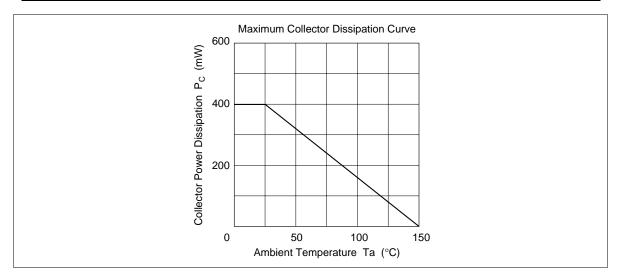
### **Absolute Maximum Ratings** (Ta = $25^{\circ}$ C)

Item	Symbol	Ratings	Unit	
Collector to base voltage	V <sub>CBO</sub>	20	V	
Collector to emitter voltage	V <sub>CEO</sub>	12	V	
Emitter to base voltage	V <sub>EBO</sub>	3	V	
Collector current	Ι <sub>c</sub>	50	mA	
Collector power dissipation	Pc	400	mW	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

#### **Electrical Characteristics** (Ta = 25°C)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	20	-	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	12	_	_	V	$I_c = 1 \text{ mA}, R_{BE} = \infty$
Emitter cutoff current	I <sub>EBO</sub>	_	—	10	μA	$V_{EB} = 3 \text{ V}, \text{ I}_{C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	—	0.5	μA	$V_{CB} = 15 \text{ V}, \text{ I}_{C} = 0$
DC current transfer ratio	h <sub>FE</sub>	30	90	200		$V_{ce} = 5 \text{ V}, \text{ I}_{c} = 20 \text{ mA}$
Collector output capacitance	Cob	—	1.0	1.5	pF	$V_{CB} = 5 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f <sub>T</sub>	3.5	4.5	_	GHz	$V_{ce} = 5 \text{ V}, \text{ I}_{c} = 20 \text{ mA}$
Power gain	PG	—	8.2	_	dB	$V_{ce} = 5 \text{ V}, \text{ I}_{c} = 20 \text{ mA},$ f = 900 MHz
Noise figure	NF		2.0	_	dB	$V_{ce}$ = 5 V, I <sub>c</sub> = 5 mA, f = 900 MHz

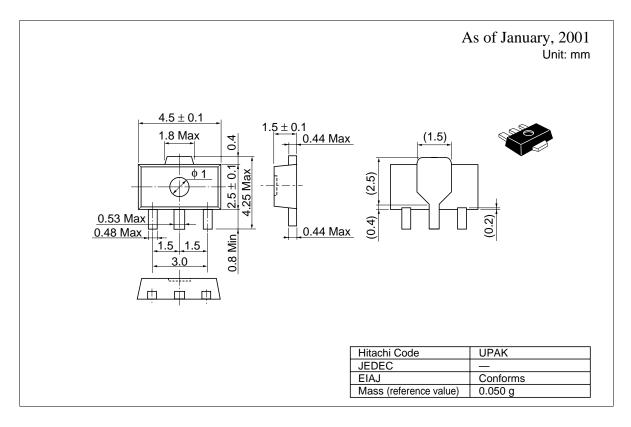
See characteristic curves of 2SC3127.



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#### 2SC3338

#### **Package Dimensions**



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